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CURRENT/TRANSIMPEDANCE AMPLIFIERS

Ultra-Low-Noise Amplifiers
For High-Speed Precision Measurements



CURRENT AMPLIFIERS
VOLTAGE AMPLIFIERS
GHZ-WIDEBAND AMPLIFIERS
PHOTORECEIVERS
LOCK-IN AMPLIFIERS
ACCESSORIES



DDPCA-300 Variable Gain Ultra-Low-Noise Current Amplifier



- 0.4 fA peak-to-peak noise
- Variable transimpedance gain from 10⁴ to 10¹³ V/A
- 240 dB dynamic range for sub-fA to mA measurements
- Adjustable bias voltage
- Compact and highly EMI-shielded case for use close to the signal source
- Manual and remote control

APPLICATIONS

Photo and ionization detector amplifier | I/V characterization of MOS and JFET structures | measurement of ultra-low currents | Quantum and biotech experiments | Spectroscopy | High resistance measurements | Easy-to-use FEMTO® amplifier add-on to existing digital voltmeter or A/D converter

DLPCA-200 Variable Gain Low-Noise Current Amplifier



- Variable transimpedance gain from 10³ to 10¹¹ V/A
- Input noise down to 4.3 fA/√Hz
- Bandwidth up to 500 kHz
- Rise time down to 700 ns
- Adjustable bias voltage
- Manual and remote control

APPLICATIONS

Photodetector amplifier | Scanning tunneling microscopy (STM) | Spectroscopy | Beam monitoring for particle accelerators/synchrotrons | Ionization detectors | Preamplifier for lock-ins, A/D converters, etc.

DHPCA-100 Variable Gain High-Speed Current Amplifier



- Variable transimpedance gain from 10² to 10⁸ V/A
- Bandwidth up to 200 MHz
- Rise time down to 1.8 ns
- Adjustable bias voltage
- Manual and remote control

APPLICATIONS

Photodetector amplifier | Fast ionization detection | Spectroscopy | Preamplifier for oscilloscopes, A/D converters and RF lock-in amplifiers



DDPCA-300 Sub-Femto Ampere Sensitivity

Model	DDPCA-30	00								
Transimpedance [V/A]	104	0^4 10^5 10^6 10^7 10^8 10^9 10^{10} 10^{11} 10^{12} 10^{13}							10 ¹³	
Bandwidth* (-3 dB) [Hz]	400	400	400	400	150	150	20	20	1	1
Rise Time* (10 % - 90 %) [ms]	8.0	0.8	0.8	0.8	2.3	2.3	17	17	350	350
Equ. Input Noise [/ \sqrt{Hz}]	45 pA	5 pA 45 pA 0.45 pA 0.45 pA 15 fA 15 fA 1.3 fA 1.3 fA 0.2 fA 0.2 fA							0.2 fA	
Accuracy	Transimped	Transimpedance (Gain) ±1 %								
Low Pass Filter	3 settings:	3 settings: full bandwidth, 0.7 Hz and 0.1 Hz								
Output Range	±10 V, ±30	±10 V, ±30 mA								
Bias Voltage Range	±10 V, max	k. 10 mA, conn	ected to ampl	fier input, adj	ustable by trin	npot or remote	control voltag	ge		
Power Supply	±15 V, +70	$\pm 15 \text{ V}$, $\pm 70 \text{ mA}$ / $\pm 15 \text{ mA}$ typ.								
Control Interface	4 opto-isolated digital inputs, TTL/CMOS compatible, analog voltage input for bias control									
Case	170 x 60 x	45 mm (L x W	x H), weight 3	320 g (0.74 lb	s)					

^{*} The values for bandwidth, rise time and integrated input noise stated in the table above are achieved with the low pass filter set to full bandwidth. Lower noise values can be achieved by setting the low pass filter to 0.7 Hz or 0.1 Hz. The minimum of 0.4 fA peak-to-peak noise is achieved in the gain settings 10¹² and 10¹³ V/A with the low pass filter set to 0.1 Hz.

Offset adjustable by potentiometer. Overload indication by LED and digital control output. Input protected against ±2 kV transients. Output short-circuit protected. Power supply via 3-pin Lemo® socket, a mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet or contact FEMTO®.

DLPCA-200 Broad Application Range

Model	DLPCA	-200												
Performance Range	Low No	ise						High Spe	eed					
Transimpedance [V/A]	10 ³	10 ⁴	10 ⁵	10^{6}	10^{7}	108	10 ⁹	10 ⁵	10^{6}	10^{7}	108	10 ⁹	1010	1011
Bandwidth (-3 dB) [kHz]	500	500	400	200	50	7	1.1	500	500	400	200	50	7	1.1
Rise Time (10 % - 90 %)	700 ns	700 ns	900 ns	1.8 µs	7 µs	50 µs	300 µs	700 ns	700 ns	900 ns	1.8 µs	7 µs	50 µs	300 µs
Equ. Input Noise [/√Hz]	20 pA	2.3 pA	450 fA	130 fA	43 fA	13 fA	4.3 fA	13 pA	1.8 pA	440 fA	130 fA	43 fA	13 fA	4.3 fA
Accuracy	Transim	pedance	(Gain) ±1	%										
Low Pass Filter	2 setting	gs: full ba	ndwidth a	nd 10 Hz										
Output Range	±10 V,	±30 mA												
Bias Voltage Range	±10 V, ı	max. 22 m	nA, conne	cted to sh	nield of B	NC input s	socket, swi	itchable to	GND					
Power Supply	±15 V,	+120 mA	/ -80 m/	A typ.										
Control Interface	5 opto-i	solated di	gital input	ts, TTL/CI	MOS com	patible, a	nalog volta	age input f	or offset c	ontrol				
Case	170 x 6	0 x 45 mı	n (L x W x	(H), weig	ht 320 g	(0.74 lbs)								

Offset adjustable by potentiometer or external control voltage. LED overload indication. Input protected against ±3 kV transients. Output short-circuit protected. Power supply via 3-pin Lemo® socket, a mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet or contact FEMTO®.

DHPCA-100 MHz Speed

Model	DHPCA-	100										
Performance Range	Low Nois	е					High Spee	ed				
Transimpedance [V/A]	10 ²	10^{3}	10^{4}	10 ⁵	10^{6}	10^{7}	10^{3}	10 ⁴	10 ⁵	10^{6}	10 ⁷	10 ⁸
Bandwidth (-3 dB) [MHz]	200	80	14	3.5	1.8	0.22	175	80	14	3.5	1.8	0.22
Rise Time (10 % - 90 %)	1.8 ns	4.4 ns	25 ns	0.1 µs	0.2 μs	1.6 µs	2.0 ns	4.4 ns	25 ns	0.1 µs	0.2 μs	1.6 µs
Equ. Input Noise [/√Hz]	220 pA	17 pA	2.2 pA	490 fA	140 fA	51 fA	155 pA	6.1 pA	1.5 pA	440 fA	140 fA	51 fA
Accuracy	Transimp	Transimpedance (Gain) ±1 %										
Low Pass Filter	3 settings	3 settings: full bandwidth, 10 MHz and 1 MHz										
Output Range	±1 V @ 5	± 1 V @ 50 Ω load										
Bias Voltage Range	±10 V, m	ax. 22 mA,	connected	to BNC-sh	ield, switch	able to GNE)					
Power Supply	±15 V, +	110 mA / -	-90 mA									
Control Interface	7 opto-is	olated digit	al inputs, T	TL/CMOS c	ompatible,	analog volta	age input fo	r offset cor	itrol			
Case	170 x 60	x 45 mm (LxWxH),	weight 320	g (0.74 lb	s)						

Offset adjustable by potentiometer or external control voltage. LED overload indication. Input protected against ±3 kV transients. Output short-circuit protected. Power supply via 3-pin Lemo® socket, a mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet or contact FEMTO®.



LCA Series Ultra Low-Noise Current Amplifier



- Input noise down to 180 aA/√Hz
- Bandwidth up to 400 kHz
- Gain up to 10¹³ V/A
- Flat frequency response
- EMI-shielded case

APPLICATIONS

Photodetector amplifier | Spectroscopy | Scanning tunneling microscopy (STM) | Ionization detectors | Pyro- and piezoelectric detectors

Model	-3 dB Bandwidth (DC)	Noise Current [/√Hz]	Transimpedance (Gain)	Rise/Fall Time
LCA-2-10T	2 Hz	0.18 fA	10 ¹² and 10 ¹³ V/A	200 ms
LCA-30-1T	30 Hz	0.5 fA	1 x 10 ¹² V/A	12 ms
LCA-30-200G	30 Hz	0.5 fA	2 x 10 ¹¹ V/A	12 ms
LCA-200-100G	200 Hz	1.5 fA	1 x 10 ¹¹ V/A	2 ms
LCA-200-10G	200 Hz	1.5 fA	1 x 10 ¹⁰ V/A	2 ms
LCA-1K-5G	1 kHz	3 fA	5 x 10 ⁹ V/A	400 μs
LCA-2K-2G	2 kHz	4.5 fA	2 x 10 ⁹ V/A	200 μs
LCA-4K-1G	4 kHz	6.5 fA	1 x 10 ⁹ V/A	100 μs
LCA-10K-500M	10 kHz	10 fA	5 x 10 ⁸ V/A	40 µs
LCA-20K-200M	20 kHz	14 fA	2 x 10 ⁸ V/A	20 μs
LCA-40K-100M	40 kHz	19 fA	1 x 10 ⁸ V/A	10 µs
LCA-100K-50M	100 kHz	30 fA	5 x 10 ⁷ V/A	4 μs
LCA-200K-20M	200 kHz	40 fA	2 x 10 ⁷ V/A	2 μs
LCA-400K-10M	400 kHz	65 fA	1 x 10 ⁷ V/A	1 μs

NOTE: Bandwidth and frequency response are independent of detector capacitance. Guaranteed and 100 % tested up to 10 nF for each amplifier (up to 1 nF for LCA-400K-10M).

Output voltage ± 10 V @ >10 k Ω load. Offset adjustable by trimpot. Output short-circuit protected. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet or contact FEMTO®.

HCA Series High-Speed Current Amplifier



- Input noise down to 270 fA/√Hz
- Bandwidth up to 400 MHz
- Gain up to 10⁶ V/A
- Flat frequency response
- Stabilized and adjustable bias voltage output for biasing external photodiodes
- EMI-shielded case

APPLICATIONS

Fast detection with large area photodiodes | Spectroscopy | Photodetection with PMTs and photodiodes | Ionization detectors | Pyro- and piezoelectric detectors

Model	-3 dB Band- width (DC)	Noise Current [/√Hz]	Transim- pedance (Gain)	Rise/ Fall Time	Max. Source Capaci- tance
HCA-1M-1M	1 MHz	270 fA	1 x 10 ⁶ V/A	350 ns	50 pF
TIGA-TIVI-TIVI		-			•
HCA-1M-1M-C	1 MHz	3.5 pA	1 x 10 ⁶ V/A	350 ns	2 nF
HCA-2M-1M	2 MHz	340 fA	1 x 10 ⁶ V/A	180 ns	25 pF
HCA-2M-1M-C	2 MHz	3.5 pA	1 x 10 ⁶ V/A	180 ns	1 nF
HCA-4M-500K	4 MHz	490 fA	5 x 10 ⁵ V/A	90 ns	15 pF
HCA-4M-500K-C	4 MHz	3.5 pA	5 x 10⁵ V/A	90 ns	500 pF
HCA-10M-100K	10 MHz	1.1 pA	1 x 10 ⁵ V/A	35 ns	15 pF
HCA-10M-100K-C	10 MHz	3.5 pA	1 x 10 ⁵ V/A	35 ns	150 pF
HCA-20M-100K-C	20 MHz	3.5 pA	1 x 10 ⁵ V/A	18 ns	50 pF
HCA-40M-100K-C	40 MHz	3.7 pA	1 x 10 ⁵ V/A	10 ns	30 pF
HCA-100M-50K-C	100 MHz	3.8 pA	5 x 10 ⁴ V/A	3.5 ns	20 pF*
HCA-200M-20K-C	200 MHz	4.9 pA	2 x 10 ⁴ V/A	1.9 ns	8 pF*
HCA-400M-5K-C	400 MHz	21 pA	5 x 10 ³ V/A	1 ns	10 pF*

Output voltage ± 1.5 V, @ 50 Ω load. Offset adjustable by trimpot. Output short-circuit protected. Adjustable bias-output (-12 V ... +12 V) for biasing photodetectors. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

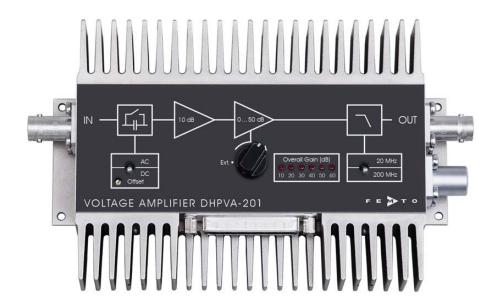
NOTE: The maximum detector capacitance listed above means that up to this value the specified —3dB-bandwidth (±15 %) is guaranteed. Larger capacitances are also possible, but will slightly influence the bandwidth and frequency response.

* For the ultra fast models HCA-100M-50K-C, HCA-200M-20K-C and HCA-400M-5K-C a reduction in bandwidth up to 25 % of the nominal values might occur if the source capacitance reaches the above noted maximum source capacitance values. Especially for these models short cables at the input and the use of low capacitance sources is of major importance. For further information please view the datasheet or contact FEMTO®.



VOLTAGE AMPLIFIERS

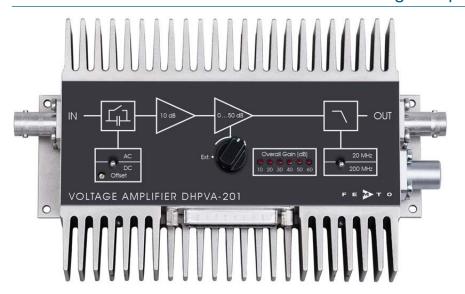
Variable Gain Wideband Amplifiers



CURRENT AMPLIFIERS VOLTAGE AMPLIFIERS GHZ-WIDEBAND AMPLIFIERS PHOTORECEIVERS LOCK-IN AMPLIFIERS		
GHZ-WIDEBAND AMPLIFIERS PHOTORECEIVERS	CURRENT AMPLIFIERS	
AMPLIFIERS PHOTORECEIVERS	VOLTAGE AMPLIFIERS	
	S	
LOCK-IN AMPLIFIERS	PHOTORECEIVERS	
	LOCK-IN AMPLIFIERS	
ACCESSORIES	ACCESSORIES	



DHPVA Series 100/200 MHz Wideband Voltage Amplifiers



- Bandwidth DC to 100 or 200 MHz independent of chosen gain setting
- Variable gain from 10 to 60 dB (× 3 to × 1,000)
- Input noise 2.3 nV/√Hz
- DC drift only 0.3 µV/°C
- True DC coupling, switchable to AC
- Switchable 10 or 20 MHz low pass filter for minimizing wide band noise
- Local and remote control

APPLICATIONS

Oscilloscope and transient recorder preamplifier | Photomultiplier amplifier | Signal booster for optical receivers and current amplifiers | Time-resolved pulse and transient measurements | Automated measurement systems

HVA Series Wideband Voltage Amplifiers

- Bandwidth DC to 10, 200 or 500 MHz
- Fixed or variable gain up to 60 dB (× 1,000)
- Noise down to 0.9 nV/√Hz
- True DC coupling, switchable to AC
- 50 Ω bipolar or 1 MΩ FET input stage

APPLICATIONS

Oscilloscope and transient recorder preamplifier | Photomultiplier and microchannel plate amplifier | Time-resolved pulse and transient measurements | Amplification of digital signals (no baseline shift at any digital code)



DLPVA Series Low-Frequency Voltage Amplifiers



- Bandwidth DC to 100 kHz
- Variable gain up to 100 dB (× 100,000)
- Input noise down to 0.4 nV/√Hz
- DC-drift down to 0.5 µV/°C
- True DC coupling, switchable to AC
- Input impedance up to 1 TΩ
- Local and remote control

APPLICATIONS

Universal low-frequency amplifier | Automated measurements | Industrial sensors | Detector preamplifier | Integrated measurement systems



DHPVA Series Reference Class from DC to 200 MHz

Model	DHPVA-101	DHPVA-201
Lower Cut-Off Frequency	DC/10 Hz, switchable	DC/10 Hz, switchable
Upper Cut-Off Frequency	10/100 MHz, switchable	20/200 MHz, switchable
Gain [dB]	10/20/30/40/50/60, switchable	10/20/30/40/50/60, switchable
Input Voltage Noise	2.3 nV/√Hz	2.3 nV/√Hz
Input Voltage Drift	0.3 μV/°C	0.3 μV/°C
Input/Output	50 Ω, BNC	50 Ω, BNC
Input Return Loss S11	-31 dB @ 100 MHz	−22 dB @ 200 MHz
Output Return Loss S22	−35 dB @ 100 MHz	−30 dB @ 200 MHz
Output Voltage	±1 V @ 50 Ω	
Monitor Output	DC - 100 kHz monitor output at D-Sub connector, gain of 1	
Digital Control	5 opto-isolated digital inputs, TTL/CMOS compatible	
Power Requirements	±15 V, ±120 mA typ.	
Dimensions	175 x 105 x 45 mm (L x W x H), weight 560 g (1.24 lbs)	

Offset adjustable by trimpot or external control voltage. Indication of selected gain setting by LEDs. Output short-circuit protected. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply series PS-15 available. For further information please see the datasheet.

The new improved models DHPVA-101 and DHPVA-201 replace the previous models DHPVA-100 and DHPVA-200. They are fully compatible delivering at least the same or better electrical performance. The heatsinks may be removed if adequate alternative cooling is provided like mounting the amplifier to a sufficiently large case/rack system.

HVA Series True DC-Coupling with Zero Output Offset

Model	HVA-10M-60-B	HVA-10M-60-F	HVA-200M-40-B	HVA-200M-40-F	HVA-500M-20-B	
Lower Cut-Off Frequency	DC/1 kHz	DC/1 Hz	DC/1 kHz	DC/1 Hz	DC	
Upper Cut-Off Frequency	10 MHz	10 MHz	200 MHz	200 MHz	500 MHz	
Gain [dB]	40/60	40/60	20/40	20/40	20	
Input Voltage Noise	0.9 nV/√Hz	4.7 nV/√Hz	1.2 nV/√Hz	4.5 nV/√Hz	3.0 nV/√Hz	
Input Voltage Drift	1 μV/°C	2 μV/°C	1 μV/°C	5 μV/°C	10 μV/°C	
Input	50 Ω, BNC	1 MΩ, BNC	50 Ω, BNC	1 MΩ, BNC	50 Ω, BNC	
Output	50 Ω, BNC	50 Ω, BNC	50 Ω, BNC	50 Ω, BNC	50 Ω, BNC	
Output Voltage	± 3.5 V @ 50 Ω	± 3.5 V @ 50 Ω	± 1 V @ 50 Ω	± 1 V @ 50 Ω	± 1 V @ 50 Ω	
Power Requirements	±15 V, ±70 mA typ.					
Dimensions	112 x 51 x 33 mm (L x W x H), weight 200 g (0.5 lbs)					

Offset adjustable by trimpot. Output short-circuit protected. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

DLPVA Series High Gain up to 100 dB

 ± 15 V, ± 75 mA typ.

175 x 51 x 34 mm (L x W x H), weight 320 g (0.7 lbs)

Power Requirements

Dimensions

Model	DLPVA-100-BUN-S	DLPVA-100-BLN-S	DLPVA-100-B-S	DLPVA-100-B-D	DLPVA-100-F-S	DLPVA-100-F-D
Input stage	Single ended, bipolar	Single ended, bipolar	Single ended, bipolar	True diff., bipolar	Single ended, FET	True diff., FET
Input	1 kΩ, BNC	1 MΩ, BNC	1 MΩ, BNC	1 MΩ, Lemo®	1 TΩ, BNC	1 TΩ, Lemo®
Typical Source Impedance	<50 Ω	<100 Ω	<1 kΩ	<1 kΩ	<1 GΩ	<1 GΩ
Lower Cut-Off Frequency	1.5 Hz (AC only)	DC/1.5 Hz	DC/1.5 Hz	DC/1.5 Hz	DC/1.5 Hz	DC/1.5 Hz
Upper Cut-Off Frequency	1/100 kHz	1/100 kHz	1/100 kHz	1/100 kHz	1/100 kHz	1/100 kHz
Gain [dB]	40/60/80/100	40/60/80/100	20/40/60/80	20/40/60/80	20/40/60/80	20/40/60/80
Input Voltage Noise	0.4 nV/√Hz	0.7 nV/√Hz	2.4 nV/√Hz	3.6 nV/√Hz	5.5 nV/√Hz	6.9 nV/√Hz
Input Voltage Drift	-	0.5 μV/°C	0.7 μV/°C	0.7 μV/°C	1.3 μV/°C	1.3 μV/°C
CMRR	-	-	-	120 dB max.	-	120 dB max.
Output	$<$ 100 Ω , BNC (terminat	e with $> 10 \text{ k}\Omega$ load for b	est performance)			
Output Voltage	$\pm 10 \text{ V} (@ > 10 \text{ k}\Omega \text{ load})$					
Digital Control	3 or 4 digital inputs and 1 digital output, opto-isolated, TTL/CMOS compatible					

Offset adjustable by trimpot or external control voltage. Indication of selected gain setting by LED. Output short-circuit protected. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.



HLVA-100 Logarithmic Wideband Voltage Amplifier



- Wide dynamic range up to 80 dB
- DC coupled, rectifying* input
- Switchable input range from ±20 μV to ±200 mV and from ±200 μV to ±2 V
- Rise/fall time 5 ns
- Input noise 2 nV/√Hz
- Local and remote control
- Integrated sample and hold baseline correction

APPLICATIONS

LIDAR systems | Signal compression | Time-resolved pulse and transient measurements | Mass spectroscopy | Particle detection

Model	HLVA-100	
Input Voltage Range	from $\pm 20~\mu V$ to $\pm 200~mV$ and from $\pm 200~\mu V$ to $\pm 2~V$, switch	chable
Dynamic Range	Typ. 60 dB (for accurate amplitude measurement) Max. 80 dB (for signal detection)	
Scaling	12.5 mV/dB, 250 mV/decade (@ 50 Ω load)	
Linearity	±1 dB (for pulse of min. 20 ns pulse width)	
Input Voltage Noise	2 nV/√Hz	
Input Voltage Drift	0.6 μV/°C	
Input/Output	50 Ω, BNC	
Rise/Fall Time	5 ns @ 40 dB step	
Output Voltage Range	+50 to +1075 mV typ. @ 50 Ω load (if output is adjusted to	o 1 V at 100 mV input)
Output Offset Voltage Range	±500 mV, adjustable by offset-trimpot	
Baseline Correction	Acquisition time	30 μs (min. sample pulse width)
	Baseline hold droop rate	1 μV/s (typ. @ 25°C)
	Loop cut-off frequency	1.5 kHz
Digital Control	2 opto-isolated digital inputs, TTL/CMOS compatible	
Power Requirements	±15 V, +90 mA/-120 mA typ.	
Dimensions	171 x 57 x 34 mm (L x W x H), weight 320 g (0.7 lbs)	

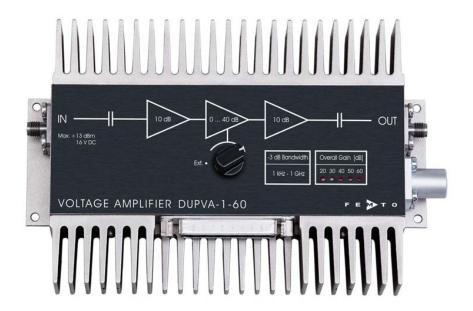
Offset adjustable by trimpot or external control voltage. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

^{*}The logarithm of a negative number is not defined as real number. Therefore the negative part of an input signal is rectifyed prior to applying the logarithmic amplification.



GHZ-WIDEBAND AMPLIFIERS

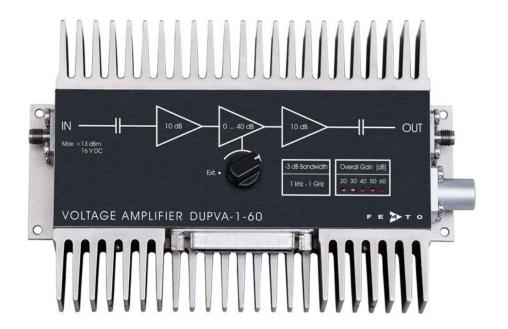
Suitable as Current and Voltage Amplifiers



CURRENT AMPLIFIERS
VOLTAGE AMPLIFIERS
GHZ-WIDEBAND AMPLIFIERS
PHOTORECEIVERS
LOCK-IN AMPLIFIERS
ACCESSORIES



DUPVA Series 1 GHz Variable Gain Voltage Amplifiers



- Variable gain up to 70 dB (approx. × 3000), switchable in 10 dB steps
- Bandwidth 1 kHz to 1.2 GHz
- Bandwidth independent of gain setting (guaranteed)
- Noise figure down to 1.9 dB (330 pV/√Hz)
- Local and remote gain control

APPLICATIONS

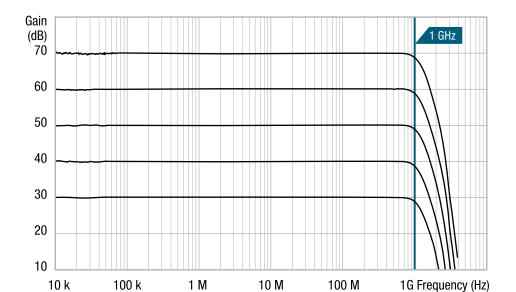
Oscilloscope and transient recorder preamplifier | Photomultiplier and microchannel plate amplifier | Signal booster for optical receivers and current amplifiers | Time-resolved pulse and transient measurements | Automated measurement systems

Model	DUPVA-1-60	DUPVA-1-70		
Lower Cut-Off-Frequency	1 kHz	1 kHz		
Upper Cut-Off-Frequency	1.2 GHz	1.1 GHz		
Rise/Fall Time	380 ps	390 ps		
Gain	20/30/40/50/60 dB	30/40/50/60/70 dB		
Input Noise	NF 3.0 dB (450 pV/√Hz)	NF 1.9 dB (330 pV/√Hz)		
Output Power	13 dBm (-1 dB compression @ 100 MHz)	12 dBm (-1 dB compression @ 100 MHz)		
Power Requirements	± 15 V, $+350$ mA / -100 mA , typ.	± 15 V, $+250$ mA / -100 mA, typ.		
Input/Output	50 Ω, SMA connector			
Monitor Output	DC - 100 kHz monitor output at D-Sub connector, gain of 1			
Control Interface	3 opto-isolated digital inputs, TTL/CMOS compatible			
Dimensions	165 x 105 x 45 mm (L x W x H), weight 510 g (1.1 lbs)			

Indication of selected gain setting by LED. Output short-circuit protected. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

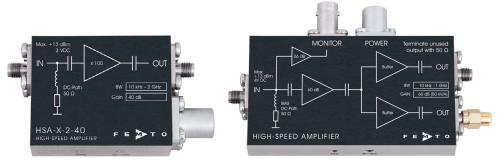
TYPICAL PERFORMANCE CHARACTERISTICS

- Bandwidth independent of gain setting (guaranteed), see figure: DUPVA-1-70 gain vs. frequency
- Upper cut-off frequency rolloff: 40 dB/oct.





HSA Series High-Speed GHz Amplifiers



APPLICATIONS

Preamplifier for ultra-fast detectors (microchannel plates, photomultipliers, avalanche photodiodes and PIN photodiodes) | Oscilloscope and spectrum/network analyzer preamplifier | Time-resolved pulse and transient measurements | Signal booster in 50 Ω high-speed systems

- Ultra-wide bandwidth from 10 kHz up to 2.5 GHz
- Gain up to 60 dB (× 1,000)
- Transimpedance gain with photodetectors up to 50,000 V/A
- Very low input noise down to $310 \text{ pV}/\sqrt{\text{Hz}}$ (6.2 pA/ $\sqrt{\text{Hz}}$)
- Integrated DC-current path for biased photodetector applications

Only HSA-Y series:

- Two identical signal outputs
- DC-monitor output

HSA-X Models	HSA-X-1-40	HSA-X-2-20	HSA-X-2-40	HSA-X-I-2-40		
Lower Cut-Off-Frequency	10 kHz	10 kHz	10 kHz	10 kHz		
Upper Cut-Off-Frequency	1.2 GHz	2.5 GHz	2.0 GHz	2.2 GHz		
Rise/Fall Time	290 ps	140 ps	180 ps	160 ps		
Gain	40 dB (× 100)	20 dB (× 10)	40 dB (× 100)	40 dB (× 100) inverting		
Transimpedance*	5,000 V/A	500 V/A	5,000 V/A	5,000 V/A inverting		
Input Noise [/ $\sqrt{\text{Hz}}$]**	310 pV (6.2 pA)	610 pV (12.2 pA)	620 pV (12.4 pA)	430 pV (8.6 pA)		
Input VSWR	1.6:1	1.23:1	1.4:1	1.25 : 1		
Maximum Output Voltage @ 50 Ω	$2\mathrm{V}_{\mathrm{pp}}$	$2V_{pp}$	1.9 V _{PP}	$2V_{pp}$		
Output VSWR	1.35:1	1.4:1	2.5:1	1.4:1		
Power Requirements	+15 V, +140 mA, typ.	+15 V, +105 mA, typ.	+15 V, +125 mA, typ.	+15 V, +140 mA, typ.		
Input/Output	50 Ω, SMA					
Dimensions	80 x 45 x 25 mm (L x W x H), weight 100 g (0.23 lb)					

HSA-Y Models	HSA-Y-1-40	HSA-Y-1-60	HSA-Y-2-20	HSA-Y-2-40			
Lower Cut-Off-Frequency	10 kHz	10 kHz	10 kHz	10 kHz			
Upper Cut-Off-Frequency	1.0 GHz	1.1 GHz	2 GHz	1.9 GHz			
Rise/Fall Time	330 ps	320 ps	175 ps	185 ps			
Gain	40 dB (× 100)	60 dB (× 1,000)	20 dB (× 10)	40 dB (× 100)			
Transimpedance*	5,000 V/A	50,000 V/A	500 V/A	5,000 V/A			
Input Noise [/√Hz]**	330 pV (6.6 pA)	330 pV (6.6 pA)	680 pV (13.6 pA)	650 pV (13 pA)			
Input VSWR	1.45:1	1.4:1	1.15:1	1.2:1			
Maximum Output Voltage @ 50 Ω	$2.0\mathrm{V}_\mathrm{pp}$	$2.3\mathrm{V}_{\mathrm{pp}}$	$2.5\mathrm{V}_\mathrm{pp}$	$1.7\mathrm{V}_{\mathrm{pp}}$			
Output VSWR	1.6:1	1.4:1	2.5:1	1.8:1			
Power Requirements	± 15 V, $+200$ / -10 mA, typ.	± 15 V, $+180$ / -10 mA, typ.	± 15 V, $+160$ / -10 mA, typ.	± 15 V, $+185$ / -10 mA, typ.			
Input	50 Ω, SMA						
Output	Two identical signal outputs, 5	Two identical signal outputs, 50 Ω , SMA					
Monitor Output	Gain: 26 dB (x 20), transimped	Gain: 26 dB (x 20), transimpedance*: 1 kV/A, output voltage range: ±10 V (R _{l cod} > 10 kΩ), bandwidth: DC - 100 kHz					
Dimensions	110 x 70 x 25 mm (L x W x H), weight 180 g (0.41 lb)					

^{*} Transimpedance = Gain \times 50 Ω (Input Impedance)

Integrated DC path for use with photodetectors. 8-32 and M4 mounting threads. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

^{**} Input Noise Current = Input Noise Voltage \div 50 Ω (Input Impedance)



PHOTORECEIVERS

From Femtowatt Sensitivity to Gigahertz Speed



CURRENT AMPLIFIERS

VOLTAGE AMPLIFIERS

GHZ-WIDEBAND AMPLIFIERS

PHOTORECEIVERS

LOCK-IN AMPLIFIERS

ACCESSORIES



OE-200 Series Variable Gain Photoreceivers



- Adjustable conversion gain from 10³ to 10¹¹ V/W
- Operating range from fW to mW
- Spectral range from 190 to 1700 nm
- NEP down to 6 fW/√Hz
- Bandwidth up to 500 kHz
- Rise time down to 700 ns
- Calibration for all fiber optic models
- Manual and remote control

APPLICATIONS

All purpose lab photoreceiver | Fiber alignment systems | Fast power monitoring | Test of laser diode to fiber coupling | Linearity measurements over 10 decades | Calibration of optical communication systems | Time-resolved pulse and power measurements | Industrial control and alignment systems

Model	0E-200-SI	0E-200-UV	0E-200-IN1	0E-200-IN2
Detector Type	Si-PIN	Si-PIN	InGaAs-PIN	InGaAs-PIN
Detector Size	Ø 1.2 mm	1.1 x 1.1 mm ²	Ø 0.3 mm (FC: Ø 0.08 mm)	Ø 0.3 mm (FC: Ø 0.08 mm)
Spectral Range	320 - 1060 nm	190 - 1000 nm	900 - 1700 nm	900 - 1700 nm
Calibration Wavelength*	850 nm	850 nm	1310 nm	1550 nm
Input Options	FST, FS, FC	FST, FS, FC	FST, FS, FC	FST, FS, FC
NEP (Dependent on Gain Setting)	8 fW/\/Hz - 33 pW/\/Hz	17 fW/√Hz - 60 pW/√Hz	7 fW/√Hz - 22 pW/√Hz	6 fW/\/Hz - 22 pW/\/Hz
Useful Operating Range	ca. 100 fW - 2 mW	ca. 200 fW - 2 mW	ca. 100 fW - 2 mW	ca. 100 fW - 2 mW

The following characteristics are valid for all models:

Performance Range	Low Noi:	se						High Sp	eed					
Conversion Gain [V/W]**	10 ³	10 ⁴	10 ⁵	10 ⁶	10 ⁷	108	10 ⁹	10 ⁵	10 ⁶	10 ⁷	10 ⁸	10 ⁹	1010	1011
Bandwidth (-3 dB) [kHz]	500	500	400	200	50	7	1.1	500	500	400	200	50	7	1.1
Rise Time (10 % - 90 %)	700 ns	700 ns	900 ns	1.8 µs	7 µs	50 µs	300 µs	700 ns	700 ns	900 ns	1.8 µs	7 µs	50 µs	300 μs
Accuracy Performance	±1 % el	ectrical be	tween set	tings, ±5 °	% electro-	optical for	FC-input,	±15 % el	ectro-optio	cal for FS-	and FST-i	nput		
Low Pass Filter	Switchal	ole to 10 H	z											
Output Performance	±10 V (±10 V (@ ≥100 kΩ load)												
Power Requirements	±15 V, +	-110 mA/-	-90 mA ty	p.										
Control Interface	5 opto-is	5 opto-isolated digital inputs, TTL/CMOS compatible, analog offset control voltage input												
Dimensions	170 x 60) x 45 mm	(L x W x I	H), weight	360 g (0.7	79 lbs)								

^{*} Since illumination conditions with the permanently mounted fiber optic connector are well defined, the FC models are delivered with a factory calibrated conversion gain. The electro optical conversion gain factors of the FST and FS free space models are set to fit nominally at the calibration wavelength.

Offset adjustable by trimpot or external control voltage. LED overload indication. Output short-circuit protected. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

Input Options

FST-Input

Free space input with 1.035"-40 threaded flange, internal threaded coupler ring included



FS-Input

Free space input with unthreaded flange (25 mm diameter)



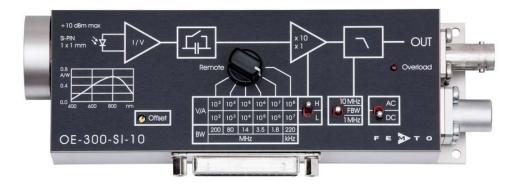
FC-Input
Permanent fiber
coupled input



^{** @} calibration wavelength



OE-300 Series 200 MHz Variable Gain Photoreceivers



APPLICATIONS

All purpose low-noise photoreceiver (O/E converter) for the MHz range | Time-resolved optical pulse and power measurements | Laser intensity noise measurements (RIN) | Optical front-end for oscilloscopes, spectrum analyzers, A/D converters and RF lock-in amplifiers

- Adjustable transimpedance gain from 10² to 10⁸ V/A
- Wide bandwidth up to 200 MHz
- Various Si and InGaAs models cover the 320 to 1700 nm wavelength range
- High dynamic input range up to 10 mW optical power
- Large optical detector size up to 3 mm diameter
- Very low noise, NEP down to 47 fW/√Hz
- Switchable low pass filters for minimizing wideband noise
- Full manual and remote control capability

Model	0E-300-SI-10	0E-300-SI-30	0E-300-IN-01	0E-300-IN-03
Detector Type	Si-PIN	Si-PIN	InGaAs-PIN	InGaAs-PIN
Detector Size [mm]	1.0 x 1.0	Ø 3.0	Ø 0.08	Ø 0.3
Spectral Range [nm]	400 - 1000	320 - 1000	900 - 1700	800 - 1700
Input Options	FST, FS	FST, FS	FC	FST, FS
NEP (Dependent on Gain Setting)	76 fW/√Hz - 322 pW/√Hz	81 fW/\/Hz - 325 pW/\/Hz	47 fW/\/Hz - 180 pW/\/Hz	52 fW/√Hz - 192 pW/√Hz

The following characteristics are valid for all models:

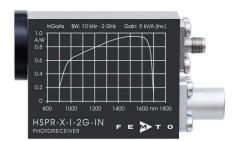
Performance Range	Low Noise						High Speed					
Gain Setting [V/A] (Transimpedance)	10 ²	10³	104	10 ⁵	10 ⁶	10 ⁷	10³	104	105	10 ⁶	10 ⁷	108
Bandwidth (-3 dB) [MHz]	200 (100)	80 (60)1	14	3.5	1.8	0.22	175 (80) ¹	80 (60)1	14	3.5	1.8	0.22
Accuracy Performance	±1 % (tran	nsimpedanc	e)									
Low Pass Filter	switchable	to 1 MHz a	nd 10 MHz									
Output Performance	±1 V (@ 5	0 Ω load), fo	or linear am	plification								
Power Requirements	±15 V, +1	±15 V, +150 mA/–100 mA typ.										
Control Interface	5 opto-isol	5 opto-isolated digital inputs, TTL/CMOS compatible, analog offset control voltage input										
Dimensions	170 x 60 x	45 mm (L	x W x H), we	eight 320 g	(0.74 lbs)							

¹⁾ model OE-300-SI-30

Offset adjustable by trimpot or external control voltage. LED overload indication. Output short-circuit protected. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.



HSPR-X and HSA-X-S Series Ultra-Fast Photoreceivers



- Wavelength range from 320 to 1700 nm
- Ultra-wide bandwidth from 10 kHz up to 2 GHz
- Max. conversion gain 4.75 x 10³ V/W
- Min. NEP 11 pW/√Hz

APPLICATIONS

Spectroscopy | Fast pulse and transient measurements | Optical triggering | Optical front-end (O/E converter) for oscilloscopes and A/D converters

Model	HSA-X-S-1G4-SI	HSPR-X-I-1G4-SI (inverting)	HSA-X-S-2G-IN	HSPR-X-I-2G-IN (inverting)	
Photodiode	Si-PIN, Ø 0.4 mm (FST, FS), integr	rated ball lens (FC)	InGaAs-PIN, Ø 0.1 mm (FST, FS), integrated ball lens (FC)		
Spectral Range	320 - 1000 nm	320 - 1000 nm	900 - 1700 nm	900 - 1700 nm	
Bandwidth (-3 dB)	10 kHz - 1.4 GHz	10 kHz - 1.4 GHz	10 kHz - 2 GHz	10 kHz - 2 GHz	
Rise/Fall Time (10 % - 90 %)	250 ps	250 ps	180 ps	180 ps	
Transimpedance Gain	5 x 10 ³ V/A	5 x 10 ³ V/A (inverting)	5 x 10 ³ V/A	5 x 10 ³ V/A (inverting)	
Conversion Gain	2.55 x 103 V/W (@ 760 nm)	2.55 x 103 V/W (@ 760 nm)	4.75 x 10 ³ V/W (@ 1550 nm)	4.75 x 10 ³ V/W (@ 1550 nm)	
NEP (@ 100 MHz)	32 pW/\/Hz (@ 760 nm)	19 pW/√Hz (@ 760 nm)	16 pW/√Hz (@ 1550 nm)	11 pW/√Hz (@ 1550 nm)	
Output VSWR	2.5 : 1	1.4:1	2.5 : 1	1.4:1	
Max. Output Voltage @ 50 Ω	1.9 V _{PP}	2.0 V _{PP}	1.9 V _{PP}	2.0 V _{PP}	
Output Noise	3.6 mV _{RMS}	2.5 mV _{RMS}	$3.6~\text{mV}_{\text{RMS}}$	2.5 mV _{RMS}	
Input Options	FST, FS, FC	FST, FS, FC	FST, FS, FC	FST, FS, FC	
Power Requirements	+15 V, 130 mA typ.	+15 V, 150 mA typ.	+15 V, 130 mA typ.	+15 V, 150 mA typ.	
Dimensions	80 x 42 x 30 mm (L x W x H), weight	ght 100 g (0.23 lbs)			

Output short-circuit protected. Threaded M4 and 8-32 mounting holes for use with standard mounting posts. Power supply +15 V via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

HCA-S-400M Series 400 MHz Photoreceivers



- Wavelength range from 320 to 1700 nm
- Bandwidth DC to 400 MHz
- Rise time 1 ns
- Max. conversion gain 4.8 x 10³ V/W

APPLICATIONS

Spectroscopy | Fast pulse and transient measurements | Optical triggering | Test of digital fiber-optic systems | Optical front-end for oscilloscopes and A/D converters

Model	HCA-S-400M-SI	HCA-S-400M-IN
Photodiode	0.8 mm Ø Si-PIN	InGaAs-PIN, Ø 0.3 mm (FST, FS), integrated ball lens (FC)
Spectral Range	320 - 1000 nm	900 - 1700 nm
Bandwidth (-3 dB)	DC - 400 MHz	DC - 400 MHz
Rise/Fall Time (10 % - 90 %)	1 ns	1 ns
Transimpedance Gain	5 x 10 ³ V/A	5 x 10 ³ V/A
Max. Conversion Gain	2.7 x 10 ³ V/W (@ 800 nm)	4.8 x 10 ³ V/W (@ 1550 nm)
NEP (@ 100 MHz)	40 pW/√Hz (@ 800 nm)	24 pW/√Hz (@ 1550 nm)
Output Noise	$3~\text{mV}_{\text{RMS}}$	3 mV _{RMS}
Input Options	FST, FS, FC, SMA	FST, FS, FC
Power Requirements	±15 V, ±55 mA typ.	
Dimensions	100 x 51 x 28 mm, v	veight 210 g (0.5 lbs)

Output voltage $\pm 1.0 \text{ V}$ (@ 50 Ω load) for linear amplification. Offset adjustable by potentiometer. Output short-circuit protected. Photoreceivers with free space input come with threaded M4 and 8-32 mounting holes for use with standard mounting posts. Power supply $\pm 15 \text{ V}$ via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.



HCA-S-200M Series 200 MHz Photoreceivers



- Wavelength range from 320 to 1700 nm
- Bandwidth from DC to 200 MHz
- Max. conversion gain 1.9 x 10⁴ V/W
- Min. NEP 5.2 pW/√Hz

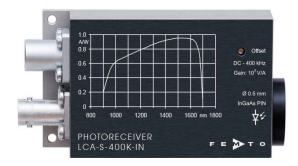
APPLICATIONS

Spectroscopy | Fast pulse and transient measurements | Optical triggering | Optical front-end for oscilloscopes, A/D converters and RF lock-in amplifiers

Model	HCA-S-200M-SI	HCA-S-200M-IN
Photodiode	0.8 mm Ø Si-PIN	InGaAs-PIN, Ø 0.3 mm (FST, FS), integrated ball lens (FC)
Spectral Range	320 - 1000 nm	900 - 1700 nm
Bandwidth (-3 dB)	DC - 200 MHz	DC - 200 MHz
Rise/Fall Time (10 % - 90 %)	1.8 ns	1.8 ns
Transimpedance Gain	2 x 10 ⁴ V/A	2 x 10 ⁴ V/A
Max. Conversion Gain	1.1 x 10 ⁴ V/W (@ 800 nm)	1.9 x 10 ⁴ V/W (@ 1550 nm)
NEP (@ 10 MHz)	9.4 pW/√Hz (@ 800 nm)	5.2 pW/√Hz (@ 1550 nm)
Output Noise	$3 \text{ mV}_{\text{RMS}}$	$4.5~\text{mV}_{\text{RMS}}$
Input Options	FST, FS, FC, SMA	FST, FS, FC
Power Requirements	± 15 V, ± 50 mA typ.	± 15 V, ± 60 mA typ.
Dimensions	105 x 51 x 28 mm, w	eight 210 g (0.5 lbs)

Output voltage ± 1.2 V (@ 50 Ω load) for linear amplification. Offset adjustable by potentiometer. Output short-circuit protected. The photoreceivers with free space input come with threaded M4 and 8-32 mounting holes for use with standard mounting posts. Power supply ± 15 V via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

LCA-S-400K Series 400 kHz Photoreceivers



- Wavelength range from 400 to 1700 nm
- Bandwidth from DC to 400 kHz
- Max. conversion gain 10⁷ V/W
- Min. NEP 75 fW/√Hz

APPLICATIONS

Spectroscopy | General purposes opto-electronic measurements | Optical front-end for oscilloscopes, A/D converters and lock-in amplifiers

Model	LCA-S-400K-SI	LCA-S-400K-IN		
Photodiode	3.0 mm Ø Si-PIN	0.5 mm Ø InGaAs-PIN		
Spectral Range	400 - 1100 nm	900 - 1700 nm		
Bandwidth (-3 dB)	DC - 400 kHz	DC - 400 kHz		
Rise/Fall Time (10 % - 90 %)	1 μs	1 μs		
Transimpedance Gain	1 x 10 ⁷ V/A	1 x 10 ⁷ V/A		
Max. Conversion Gain	5.9 x 10 ⁶ V/W (@ 920 nm)	9.5 x 10 ⁶ V/W (@ 1550 nm)		
NEP (@ 10 kHz)	120 fW/√Hz (@ 920 nm)	75 fW/√Hz (@ 1550 nm)		
Output Noise	$1.6~\text{mV}_{\text{RMS}}$	2 mV _{RMS}		
Input Options	FST, FS	FST, FS		
Power Requirements	±15 V, ±40 mA typ.			
Dimensions	100 x 51 x 28 mm, weight 210 g (0.5 lbs)			

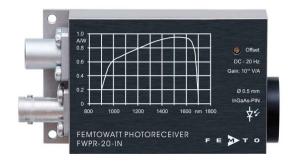
Output voltage ± 10 V max (@ 100 k Ω load). Offset adjustable by trimpot. Units with fiber optic input are optionally available. Output short-circuit protected. Threaded M4 and 8-32 mounting holes for use with standard mounting posts. Power supply ± 15 V via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

Mounting options

- The series HSPR-X/HSA-X-S, HCA-S, LCA-S, FWPR and PWPR feature both UNC 8-32 and M4 tapped holes for mounting on metric and imperial threaded standard posts.
- Optional post adapter plate PRA-PAP adds additional UNC 8-32 and M4 tapped holes to the series OE, HCA-S, LCA-S, FWPR and PWPR.



FWPR-20 Series Femtowatt Photoreceivers



APPLICATIONS

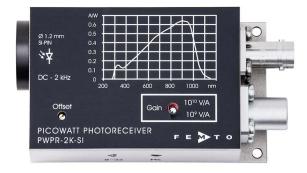
Fluorescence measurements | Spectroscopy | Electrophoresis | Chromatography | Replacement for photomultiplier tubes (PMTs), avalanche photodiodes (APDs) and liquid nitrogen cooled germanium photodiodes

- Ultra-low-noise: NEP 0.7 fW/√Hz
- Wavelength range from 320 nm to 1700 nm
- Bandwidth DC to 20 Hz
- Transimpedance amplifier with high gain up to 10¹² V/A included

Model	FWPR-20-SI	FWPR-20-IN			
Photodiode	1.1 x 1.1 mm ² Si	0.5 mm Ø InGaAs-PIN			
Spectral Range	320 - 1100 nm	900 - 1700 nm			
Bandwidth (-3 dB)	DC - 20 Hz	DC - 20 Hz			
Rise/Fall Time (10 % - 90 %)	18 ms	18 ms			
Transimpedance Gain	1 x 10 ¹² V/A	1 x 10 ¹¹ V/A			
Max. Conversion Gain	0.6 x 10 ¹² V/W (@ 960 nm)	0.95 x 10 ¹¹ V/W (@ 1550 nm)			
NEP (@ 1 Hz)	0.7 fW/√Hz (@ 960 nm)	7.5 fW/./Hz (@ 1550 nm)			
Output Noise	6 mV _{RMS}	3 mV _{RMS}			
Input Options	FST, FS	FST, FS			
Power Requirements	±15 V, ±15 mA typ.				
Dimensions	100 x 51 x 28 mm, weight 190 g (0.42 lbs)				

Output voltage $\pm 10 \text{ V}$ max (@ $100 \text{ k}\Omega$ load). Offset adjustable by potentiometer. Units with fiber optic input are optionally available. Output short-circuit protected. Threaded M4 and 8-32 mounting holes for use with standard mounting posts. Power supply $\pm 15 \text{ V}$ via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

PWPR-2K Series Picowatt Photoreceivers



APPLICATIONS

Spectroscopy, reflection and transmission measurements |
Time-resolved optical pulse and power measurements |
Characterization of light sources | Highly sensitive applications using chopper modulation | Optical front-end for oscilloscopes,
A/D converters and lock-in amplifiers

- Ultra-low-noise: NEP \leq 10 fW/ $\sqrt{\text{Hz}}$
- Wavelength range from 320 to 1700 nm
- Bandwidth DC to 2 kHz
- Transimpedance gain switchable 109 V/A, 1010 V/A

Model	PWPR-2K-SI	PWPR-2K-IN
Photodiode	1.2 mm Ø Si-PIN	0.5 mm Ø InGaAs-PIN
Spectral Range	320 - 1060 nm	900 - 1700 nm
Bandwidth (-3 dB)	DC - 2 kHz	DC - 2 kHz
Rise/Fall Time (10 % - 90 %)	165 μs	165 μs
Transimpedance Gain (switchable)	1 x 10 ⁹ V/A 1 x 10 ¹⁰ V/A	1 x 10 ⁹ V/A 1 x 10 ¹⁰ V/A
Max. Conversion Gain	0.64 x 10 ⁹ V/W (@ 900 nm, gain 10 ⁹ V/A) 0.64 x 10 ¹⁰ V/W (@ 900 nm, gain 10 ¹⁰ V/A)	1.1 x 10 ⁹ V/W (@ 1580 nm, gain 10 ⁹ V/A) 1.1 x 10 ¹⁰ V/W (@ 1580 nm, gain 10 ¹⁰ V/A)
NEP (@ 100 Hz)	9 fW/√Hz (@ 900 nm)	10 fW/./Hz (@ 1580 nm)
Output Noise	$0.45~\mathrm{mV}_\mathrm{RMS}$ @ $10^9~\mathrm{V/A}$	$0.75~\mathrm{mV}_\mathrm{RMS}$ @ $10^9~\mathrm{V/A}$
Input Options	FST, FS	FST, FS
Power Requirements	±15 V, +32 mA / –25 mA	
Dimensions	100 x 51 x 33 mm, 220 g (0.49 lbs)	

Output voltage ± 10 V max (@ 100 k Ω load). Offset adjustable by potentiometer. Output short-circuit protected. Power supply ± 15 V via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.



LOCK-IN AMPLIFIERS

Easy-to-Use High-Performance Lock-In Amplifiers For Cost-Sensitive Applications



CURRENT AMPLIFIERS

VOLTAGE AMPLIFIERS

GHZ-WIDEBAND
AMPLIFIERS

PHOTORECEIVERS

LOCK-IN AMPLIFIERS

ACCESSORIES



LIA-MV-150 Series Lock-In Amplifier Modules



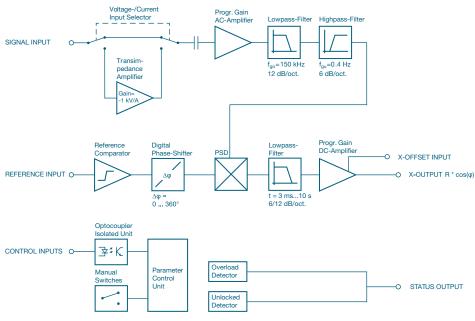
- Current and voltage input
- Working frequency up to 45 kHz
- Adjustable sensitivity, time constant and phase
- Local and remote control
- Compact and EMI-shielded case

Model	LIA-MV-150-S Standard	LIA-MV-150-D True-Differential Input
Voltage Input	BNC connector Single-ended Instrumentation amplifier Noise 12 nV/\/Hz	Lemo® connector True-differential Instrumentation amplifier Noise 12 nV/√Hz
Current Input	BNC connector Transimpedance amplifier, gain 1 kV/A Noise 13 pA/\/Hz	Lemo® connector Transimpedance amplifier, gain 1 kV/A Noise 13 pA/√Hz
Sensitivity (Full Scale)	Voltage: 3 μ V to 100 mV, switchable in 1-3-10 steps Current: 3 nA to 100 μ A, switchable in 1-3-10 steps	
Working Frequency	10 Hz - 45 kHz	
Reference Input	± 100 mV to ± 5 V, switchable to TTL	
Phase	Adjustable 0° - 360° (8-bit resolution), Temperature drift <0.01°/K	
Demodulator Dynamic Reserve	35 dB @ low drift setting, 55 dB @ high dynamic setting	
Time Constants	3 ms to 10 s, switchable in 1-3-10 steps, slope switchable 6 dE	3 or 12 dB/octave
Signal Filter	Highpass 0.4 Hz (6 dB/oct.), Lowpass 150 kHz (12 dB/oct.)	
Output	$X = in phase, \pm 10 V full scale, short-circuit protected$	
Digital Control	16 TTL, CMOS, opto-isolated 8-bit phase, 4-bit time constant, 4-bit sensitivity	
Power Supply	±15 V, 100 mA typ.	
Dimensions	170 x 60 x 30 mm (L x W x H), weight 370 g (0.82 lbs)	

Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

APPLICATIONS

Spectroscopy | Laser stabilization | Luminescence, fluorescence, phosphorescence measurements | Light scattering measurements | Opto-electronical quality control | Integration in industrial and scientific measurement systems | OEM systems





LIA-MV(D)-200 Series Lock-In Amplifiers



- Single and dual phase
- Rugged aluminum housing
- BNC connectors for input and output signals
- Working frequency 5 Hz up to 120 kHz
- Phase shifter 0° 360°
- Current and voltage input
- Optional reference oscillator module SOM-1 available

Model	LIA-MV-200-L Single Phase	LIA-MV-200-H Single Phase	LIA-MVD-200-L Dual Phase	LIA-MVD-200-H Dual Phase
Working Frequency	5 Hz - 10 kHz	50 Hz - 120 kHz	5 Hz - 10 kHz	50 Hz - 120 kHz
Time Constants	3 ms - 10 s 6 or 12 dB/oct.	300 μs - 1 s 6 or 12 dB/oct.	3 ms - 10 s 6 or 12 dB/oct.	300 μs - 1 s 6 or 12 dB/oct.
Adjustable Signal Filter (6 dB/oct.)	Highpass 0.2 Hz - 1 kHz Lowpass 100 Hz - 1 MHz	Highpass 2 Hz - 10 kHz Lowpass 100 Hz - 1 MHz	Highpass 0.2 Hz - 1 kHz Lowpass 100 Hz - 1 MHz	Highpass 2 Hz - 10 kHz Lowpass 100 Hz - 1 MHz
Outputs (BNC)	X = in phase, $\pm 10 \text{ V full scale, short-circuit } \text{g}$ Signal monitor output	protected,	X = in phase, Y = quadrature, R = magnitude, ±10 V full scale, short-circuit p Signal monitor output	protected,
Sensitivity (Full Scale)	Voltage: 3 μV - 1 V in 1-3-10 s Current: 30 pA - 10 μA in 1-3-	•		
Voltage Input (BNC)	Instrumentation amplifier, noise	e 12 nV/√Hz		
Current Input (BNC)	Transimpedance amplifier, gair	n 100 kV/A, noise 0.4 pA/√Hz		
Reference Input (BNC)	±100 mV to ±5 V, switchable to	to TTL		
Phase	Adjustable 0° - 360°; resolution Temperature drift <0.01°/K	on: 8-bit @ f ≤ 60 kHz, 7-bit @ f	> 60 kHz	
Max. Dyn. Reserve	80 dB			
Digital Control	16 TTL/CMOS inputs: 8-bit pha	ase, 4-bit time constant, 4-bit ser	nsitivity	
Power Supply	± 15 V, $+120$ mA / -60 mA			

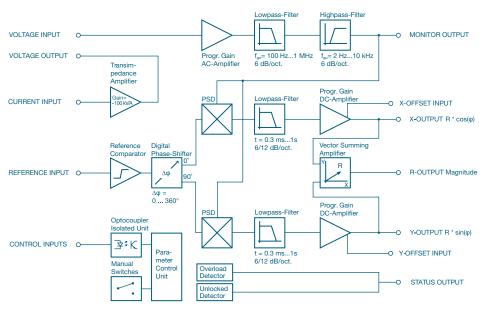
The optional Reference Oscillator SOM-1 can be connected by an extension connector inside the module. Power supply via 3-pin Lemo® socket. A mating connector is provided with the device. Optional power supply PS-15 available. For further information please view the datasheet.

223 x 105 x 65 mm (L x W x H), weight 1,000 g (2.2 lbs)

APPLICATIONS

Dimensions

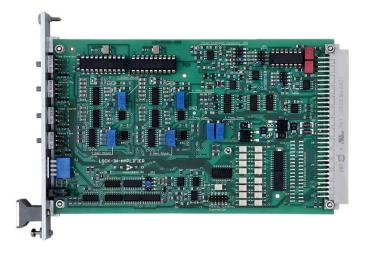
Spectroscopy | Luminescence, fluorescence, phosphorescence measurements | Light scattering measurements | Laser stabilization | Opto-electronical quality control | Integration into industrial and scientific measurement-systems | Alternative to expensive desktop lock-in amplifiers for general lab use





LIA-BV(D)-150 Series Single-Board Lock-In Amplifiers





- Single and dual phase 19" boards
- Working frequency 5 Hz up to 120 kHz
- Phase shifter 0° 360°
- Current and voltage input
- Parameter control by local switches and opto-isolated digital inputs
- Mounting kit MK-LIA-2 and reference oscillator module SOM-1 available

Model	LIA-BV-150-L Single Phase	LIA-BV-150-H Single Phase	LIA-BVD-150-L Dual Phase	LIA-BVD-150-H Dual Phase
Working Frequency	5 Hz - 10 kHz	50 Hz - 120 kHz	5 Hz - 10 kHz	50 Hz - 120 kHz
Time Constants	3 ms - 10 s 6 or 12 dB/oct.	300 μs - 1 s 6 or 12 dB/oct.	3 ms - 10 s 6 or 12 dB/oct.	300 μs - 1 s 6 or 12 dB/oct.
Signal Filter	Highpass 0.2 Hz - 1 kHz Lowpass 100 Hz - 1 MHz	Highpass 2 Hz - 10 kHz lowpass 100 Hz - 1 MHz	Highpass 0.2 Hz - 1 kHz Lowpass 100 Hz - 1 MHz	Highpass 2 Hz - 10 kHz lowpass 100 Hz - 1 MHz
Outputs	X = in phase, $\pm 10 \text{ V full scale, short-circuit } \text{Signal monitor output}$	protected,	X = in phase, Y = quadrature, R = magnitude ±10 V full scale, short-circuit Signal monitor output	protected,
Sensitivity (Full Scale)	Voltage: 3 μV - 1 V in 1-3-10 s Current: 30 pA - 10 μA in 1-3-	•		
Voltage Input	True-differential instrumentation	on amplifier, noise 12 nV/\/Hz		
Current Input	Transimpedance amplifier, gair	n 100 kV/A, noise 0.4 pA/√Hz		
Reference Input	± 100 mV to ± 5 V, switchable	to TTL		
Phase	Adjustable 0° - 360°; resolution Temperature drift <0.01°/K	on: 8-bit @ f ≤ 60 kHz, 7-bit @ f	> 60 kHz	
Max. Dyn. Reserve	80 dB			
Digital Control	16 TTL/CMOS inputs: 8-bit pha	ase, 4-bit time constant, 4-bit se	nsitivity	
Power Supply	± 15 V, $+120$ mA / -60 mA			
Dimensions	160 x 100 x 20 mm (L x W x F	H), weight 100 g (0.22 lbs)		

APPLICATIONS

Spectroscopy | Luminescence, fluorescence, phosphorescence measurements | Light scattering measurements | Opto-electronical quality control | Integration in industrial and scientific measurement-systems | Multichannel systems at an attractive price



ACCESSORIES



CURRENT AMPLIFIERS

VOLTAGE AMPLIFIERS

GHZ-WIDEBAND AMPLIFIERS

PHOTORECEIVERS

LOCK-IN AMPLIFIERS

ACCESSORIES



LUCI-10 USB Control Interface



- Compact digital I/O interface for USB remote control of FEMTO amplifiers and photoreceivers
- Supports opto-isolation of amplifier signal path from PC USB port
- Bus-powered operation
- System driver, application software and VI's for use with Lab-VIEW™ included

Model	LUCI-10
Bus Interface	USB 2.0 (full-speed)
Digital I/O Interface	16 output lines, 3 opto-isolated input lines
Supply	PC USB bus powered
Connectors	USB type A and D-Sub, 25 pin, male
Case	Zinc die-cast hood, nickel plated, with jack screws, weight 130 g (0.3 lbs)
Software, Included on CD	Device driver for Microsoft® Windows 32 bit & 64 bit operating system, Dynamic link library (DLL), Graphical user interface (GUI) programs, Sample VI's and FEMTO Library for use in LabVIEW™
System Requirements	Microsoft® Windows XP SP 3 or higher, compatible with Windows 10, Intel Pentium III or AMD Athlon or better, 1 GB RAM or more, 5 GB of hard disk space, USB 1.1 or 2.0 port
Optional Requirements	For development of own application programs a development environment like LabVIFW™ Version

2012 (or higher) or C/C++ is required.

PS-15-25-L Remote Power Supply

- Input voltage 100 240 VAC
- Output ±15 V, +500/-400 mA
- Shielded output cord with Lemo[®] plug
- Floating design to avoid ground loops
- Short-circuit protected
- Ripple typ. 15 mV_{RMS}
- Suitable for all FEMTO modules
- Available as European, Australian and US version





Accessories For Photoreceivers

All FEMTO photoreceivers offered with FS input (round flange with 25 mm diameter) are now also available with 1.035"-40 threaded flange (FST) input – for even more flexibility on the optical bench! For example converting the free-space FST input to an optical fiber input is easily done by screwing on one of the optionally available FEMTO fiber-adapters PRA-FC and PRA-FSMA.

The post adapter plate PRA-PAP expands the optical breadboard mounting options for FEMTO photoreceivers. Even for photoreceivers that are already equipped with post mounting threads the post adapter plate enlarges the mounting position options. Due to the integrated M4 and 8-32 UNC tapped holes, standard posts for breadboard systems can be easily mounted to the photoreceiver via the adapter plate.

The picture shows the PWPR-2K-SI-FST being easily turned into a fiber coupled model.



PRA-FC / PRA-FSMA Fiber-Adapters And Mounting Tool







- Compatible with all FEMTO photoreceivers with threaded 1.035"-40 free space input (FST)
- Easy mounting option for standard optical fibers
- Recommended for photosensitive areas of 0.4 mm diameter or more (coupling efficiency may be compromised for photodiodes with smaller diameter)
- Machined from solid stainless steel
- Available adapter types: PRA-FC (FC/PC, FC/APC, FC/UPC) and PRA-FSMA
- Aditionally available: spanner wrench AT-W1 for convenient mounting of the adapters

PRA-PAP Post Adapter Plate



- Compatible with FEMTO photoreceiver series FWPR, PWPR, OE, LCA-S and HCA-S
- M4 and 8-32 UNC threads suitable for standard optical mounting posts
- High-tensile material
- Mounting screws included



CAB-LN1 Series Low Noise Cables



- Minimizes triboelectric and microphonic noise
- Designed for ultra sensitive current and charge measurements
- Noise level reduction by a factor of 1,000
- Highly shielding coaxial design
- Fully assembled with premium quality connectors
- Ultra high insulation resistance $> 10^{14} \Omega$ guaranteed
- Variety of lengths available: from 10 cm to 5 m

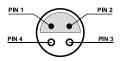
APPLICATIONS

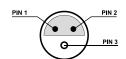
Measurements of low currents down to femtoamperes | Photodetectors and ionization detectors | High resistance measurements | Scanning probe microscopy (STM, SPM, STS) | Spectroscopy | Piezo- and pyroelectric transducers

Length	Plug BNC – BNC
0.1 m	CAB-LN1-BB-010
0.2 m	CAB-LN1-BB-020
0.5 m	CAB-LN1-BB-050
1.0 m	CAB-LN1-BB-100
1.5 m	CAB-LN1-BB-150
2.0 m	CAB-LN1-BB-200
3.0 m	CAB-LN1-BB-300
5.0 m	CAB-LN1-BB-500

Lemo® Connectors







- High quality connector
- 3-pin and 4-pin versions available
- For use with shielded cables
- Suitable for all FEMTO modules